

SNAS376C-NOVEMBER 2006-REVISED APRIL 2013

LME49710 High-Performance, High-Fidelity Audio Operational Amplifier

Check for Samples: LME49710

FEATURES

- Easily Drives 600Ω Loads
- **Optimized for Superior Audio Signal Fidelity**
- **Output Short Circuit Protection**
- PSRR and CMRR Exceed 120dB (Typ)
- SOIC, PDIP, and TO-99 Packages

APPLICATIONS

- **Ultra High-Quality Audio Amplification**
- **High-Fidelity Preamplifiers**
- **High-Fidelity Multimedia**
- State-of-the-Art Phono Pre Amps
- **High-Performance Professional Audio**
- **High-Fidelity Equalization and Crossover** Networks
- **High-Performance Line Drivers**
- **High-Performance Line Receivers**
- **High-Fidelity Active Filters**

KEY SPECIFICATIONS

- Power Supply Voltage Range: ±2.5V to ±17V
- THD+N ($A_V = 1$, $V_{OUT} = 3V_{RMS}$, $f_{IN} = 1$ kHz)
 - $R_{L} = 2k\Omega$: 0.00003% (typ)
 - $-R_{L} = 600\Omega$: 0.00003% (typ)
- Input Noise Density: 2.5nV/VHz (typ)
- Slew Rate: ±20V/µs (typ)
- Gain Bandwidth Product: 55MHz (typ)
- Open Loop Gain ($R_L = 600\Omega$): 140dB (typ)
- Input Bias Current: 7nA (typ)
- Input Offset Voltage: 0.05mV (typ)
- DC Gain Linearity Error: 0.000009%

DESCRIPTION

The LME49710 is part of the ultra-low distortion, lownoise, high-slew-rate operational amplifier series optimized and fully specified for high-performance, applications. high-fidelity Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49710 audio operational amplifiers deliver superior audio signal amplification for outstanding audio performance. The LME49710 combines extremely low-voltage noise density (2.5nV/Hz) with vanishingly low THD+N (0.00003%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49710 has a high slew rate of ±20V/µs and an output current capability of ±26mA. Further, dynamic range is maximized by an output stage that drives $2k\Omega$ loads to within 1V of either power supply voltage and to within 1.4V when driving 600Ω loads.

The LME49710's outstanding CMRR (120dB), PSRR (120dB), and V_{OS} (0.05mV) give the amplifier excellent operational amplifier DC performance.

The LME49710 has a wide supply range of ±2.5V to ±17V. Over this supply range the LME49710's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its lowinput bias current. The LME49710 is unity gain stable. The Audio Operational Amplifier achieves outstanding AC performance while driving complex loads with values as high as 100pF.

The LME49710 is available in an 8-lead narrow body SOIC, an 8-lead PDIP, and an 8-lead TO-99. Demonstration boards are available for each package.

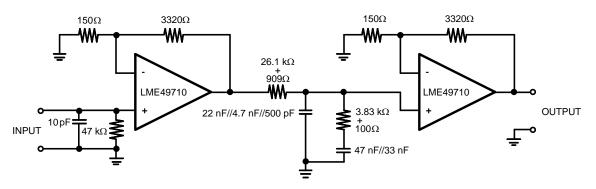


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TYPICAL APPLICATION



Note: 1% metal film resistors, 5% polypropylene capacitors

Figure 1. Passively Equalized RIAA Phono Preamplifier

CONNECTION DIAGRAMS

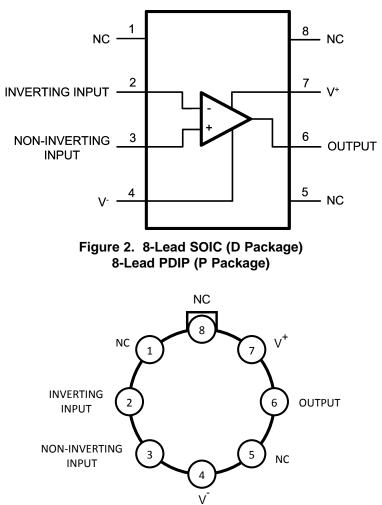


Figure 3. 8-Lead TO-99 (LMC Package)

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾⁽²⁾⁽³⁾

Power Supply Voltage ($V_S = V^+ - V^-$)		36V	
Storage Temperature	-65°C to 150°C		
Input Voltage	(V-) - 0.7V to (V+) + 0.7V		
Output Short Circuit ⁽⁴⁾	Continuous		
Power Dissipation		Internally Limited	
ESD Susceptibility ⁽⁵⁾	2000V		
ESD Susceptibility ⁽⁶⁾	200		
Junction Temperature	150°C		
	θ _{JA} (D)	145°C/W	
Thermal Desistance	θ _{JA} (P)	102°C/W	
Thermal Resistance	150°C/W		
	35°C/W		
Temperature Range $(T_{MIN} \le T_A \le T_{MAX})$	–40°C ≤ T _A ≤ 85°C		
Supply Voltage Range		$\pm 2.5 V \le V_S \le \pm 17 V$	

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

(2) Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

- (3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (4) Amplifier output connected to GND, any number of amplifiers within a package.
- (5) Human body model, 100pF discharged through a 1.5k Ω resistor.

(6) Machine Model ESD test is covered by specification EIAJ IC-121-1981. A 200pF cap is charged to the specified voltage and then discharged directly into the IC with no external series resistor (resistance of discharge path must be under 50Ω).

ELECTRICAL CHARACTERISTICS⁽¹⁾⁽²⁾

The following specifications apply for $V_S = \pm 15V$, $R_L = 2k\Omega$, $f_{IN} = 1kHz$, and $T_A = 25^{\circ}C$, unless otherwise specified.

Cumphiel	Denemerten	Conditions	LME	LME49710		
Symbol	Parameter	Conditions	Typical ⁽³⁾	ical ⁽³⁾ Limit ⁽⁴⁾⁽⁵⁾		
THD+N	Total Harmonic Distortion + Noise		0.00003 0.00003	0.00009	% (max) % (max)	
IMD	Intermodulation Distortion	$A_V = 1$, $V_{OUT} = 3V_{RMS}$ Two-tone, 60Hz & 7kHz 4:1	0.00005		% (max)	
GBWP	Gain Bandwidth Product		55	45	MHz (min)	
SR	Slew Rate		±20	±15	V/µs (min)	
FPBW	Full Power Bandwidth	$V_{OUT} = 1V_{P-P}, -3dB$ referenced to output magnitude at f = 1kHz	10		MHz	
t _s	Settling time	$A_V = 1, 10V$ step, $C_L = 100$ pF 0.1% error range	1.2		μs	
	Equivalent Input Noise Voltage	$f_{BW} = 20Hz$ to $20kHz$	0.34	0.65	μV _{RMS}	
e _n	Equivalent Input Noise Density	f = 1kHz f = 10Hz	2.5 6.4	4.7	nV /√Hz nV / √Hz	
i _n	Current Noise Density	f = 1kHz f = 10Hz	1.6 3.1		pA /√Hz pA /√H z	

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

(2) Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

(3) Typical specifications are specified at $+25^{\circ}$ C and represent the most likely parametric norm.

(4) Tested limits are specified to AOQL (Average Outgoing Quality Level).
(5) Datasheet min/max specification limits are ensured by design, test, or statistical analysis.

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EXAS

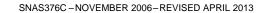
ELECTRICAL CHARACTERISTICS⁽¹⁾⁽²⁾ (continued)

The following specifications apply for $V_S = \pm 15V$, $R_L = 2k\Omega$, $f_{IN} = 1kHz$, and $T_A = 25^{\circ}C$, unless otherwise specified.

.			LME	49710	Units
Symbol	Parameter	Conditions	Typical ⁽³⁾	Limit ⁽⁴⁾⁽⁵⁾	(Limits)
V _{OS}	Offset Voltage		±0.05	±0.7	mV (max)
$\Delta V_{OS} / \Delta Temp$	Average Input Offset Voltage Drift vs Temperature	40°C ≤ T _A ≤ 85°C	0.2		µV/°C
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	$\Delta V_{\rm S} = 20 V^{(6)}$	125	110	dB (min)
I _B	Input Bias Current	$V_{CM} = 0V$	7	72	nA (max)
ΔI _{OS} /ΔTemp	Input Bias Current Drift vs Temperature	–40°C ≤ T _A ≤ 85°C	0.1		nA/°C
I _{OS}	Input Offset Current	$V_{CM} = 0V$	5	65	nA (max)
V _{IN-CM}	Common-Mode Input Voltage Range		+14.1 -13.9	(V+) - 2.0 (V-) + 2.0	V (min) V (min)
CMRR	Common-Mode Rejection	-10V <v<sub>CM<10V</v<sub>	120	110	dB (min)
Z _{IN}	Differential Input Impedance		30		kΩ
	Common Mode Input Impedance	-10V <v<sub>CM<10V</v<sub>	1000		MΩ
A _{VOL}		$-10V < V_{OUT} < 10V, R_{L} = 600\Omega$	140		dB
	Open Loop Voltage Gain	$-10V < V_{OUT} < 10V, R_L = 2k\Omega$	140	125	dB
		$-10V < V_{OUT} < 10V, R_{L} = 10k\Omega$	140		dB
		$R_L = 600\Omega$	±13.6	±12.5	V
V _{OUTMAX}	Maximum Output Voltage Swing	$R_L = 2k\Omega$	±14.0		V
		$R_L = 10k\Omega$	±14.1		V
I _{OUT}	Output Current	$R_{L} = 600\Omega, V_{S} = \pm 17V$	±26	±23	mA (min)
I _{OUT-CC}	Short Circuit Current		+53 -42		mA mA
R _{OUT}	Output Impedance	f _{IN} = 10kHz Closed-Loop Open-Loop	0.01 13		Ω Ω
C _{LOAD}	Capacitive Load Drive Overshoot	100pF	16		%
I _S	Quiescent Current	I _{OUT} = 0mA	4.8	5.5	mA (max)

(6) PSRR is measured as follows: V_{OS} is measured at two supply voltages, ±5V and ±15V. PSRR = $|20log(\Delta V_{OS}/\Delta V_S)|$.

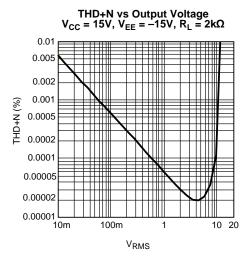




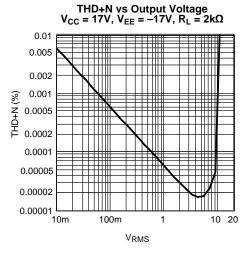


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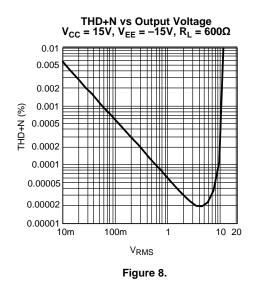
TYPICAL PERFORMANCE CHARACTERISTICS











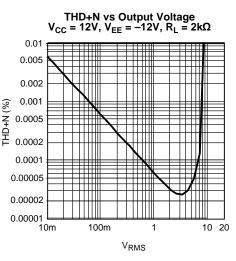
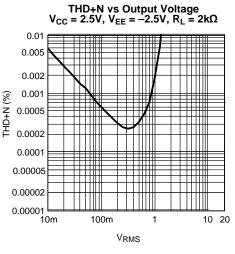
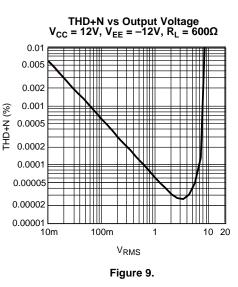


Figure 5.









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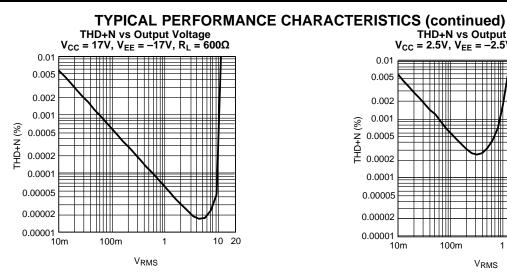
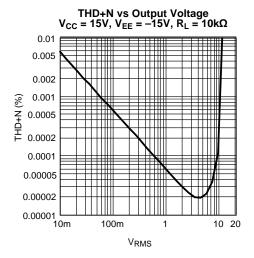
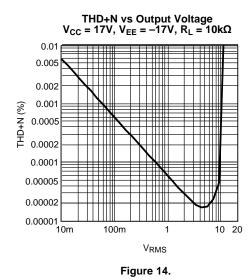


Figure 10.







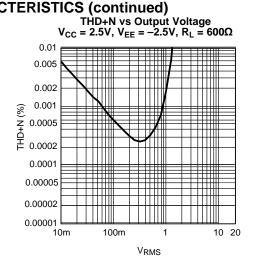
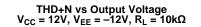


Figure 11.



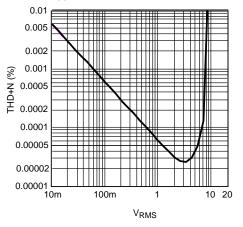
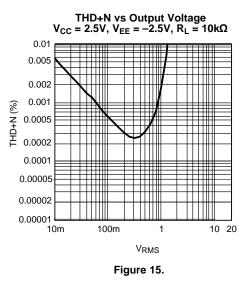


Figure 13.



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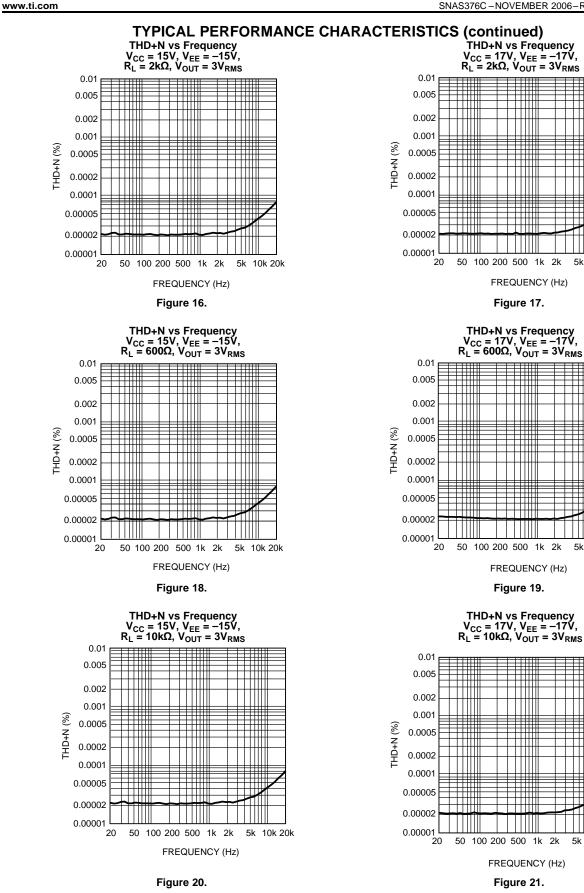


5k 10k 20k

5k 10k 20k

|||||

5k 10k 20k



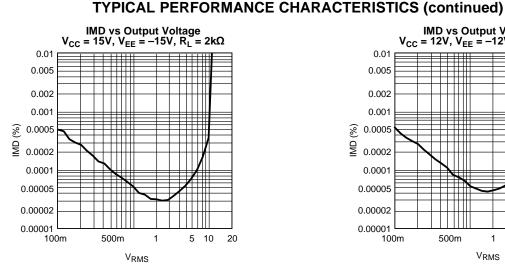
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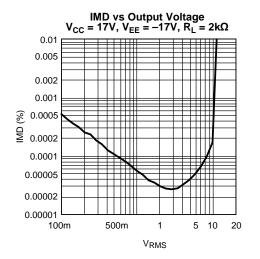
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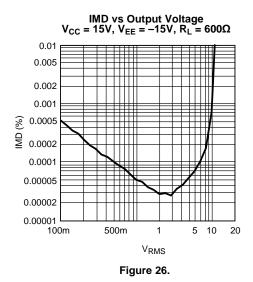
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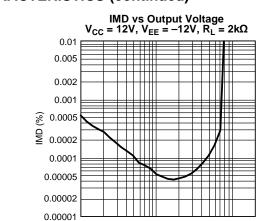












500m

100m

VRMS Figure 23.

1

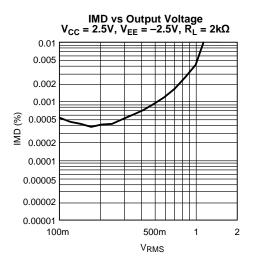
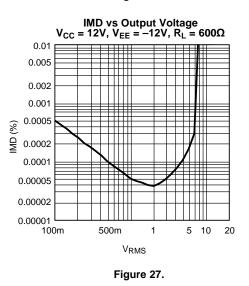


Figure 25.



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EXAS Instruments



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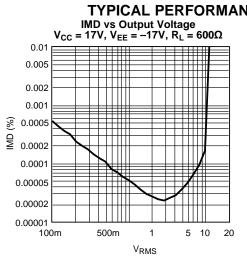
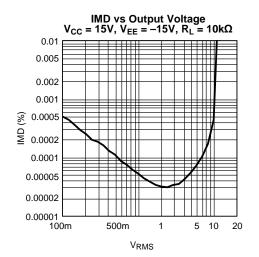
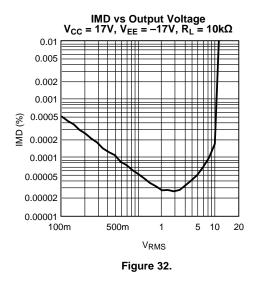


Figure 28.







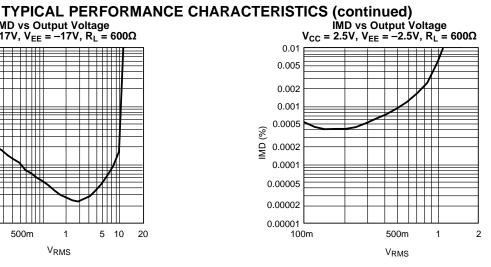
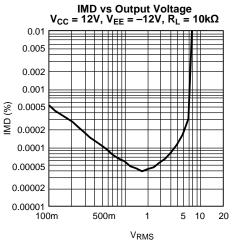
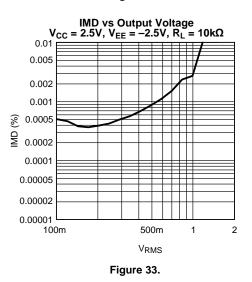


Figure 29.







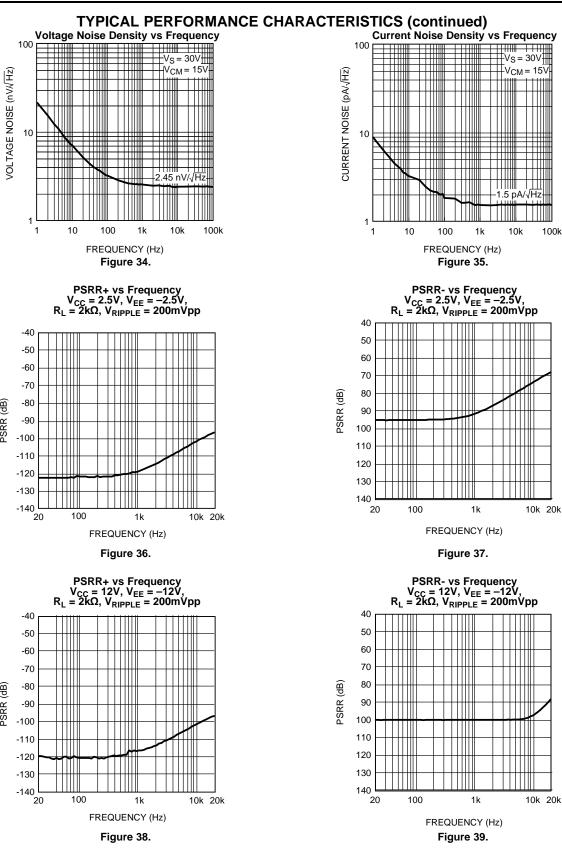
PSRR (dB)

(dB)

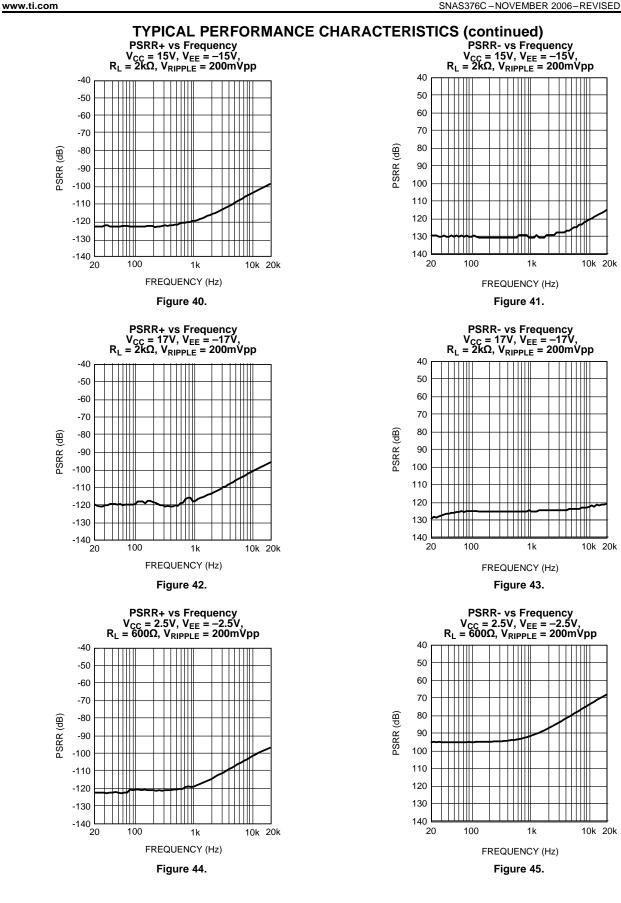
PSRR (

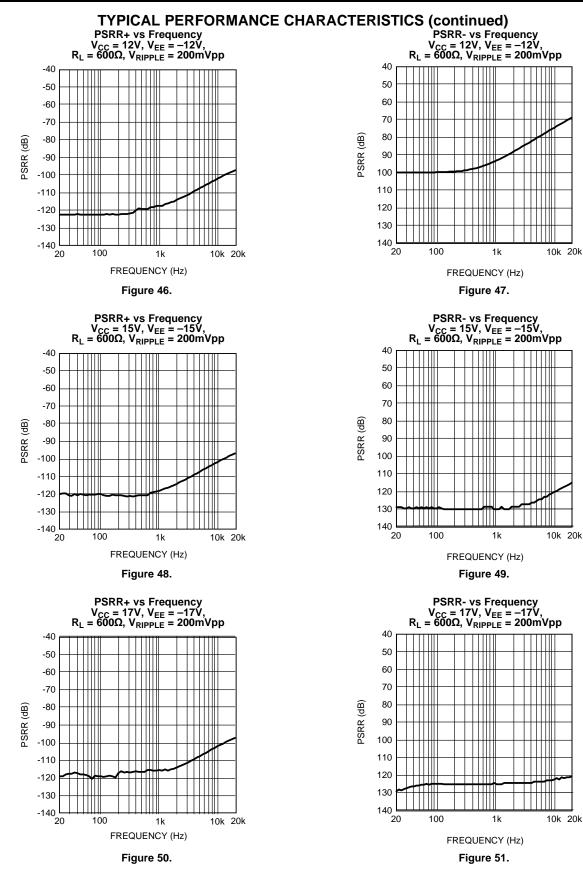
100k

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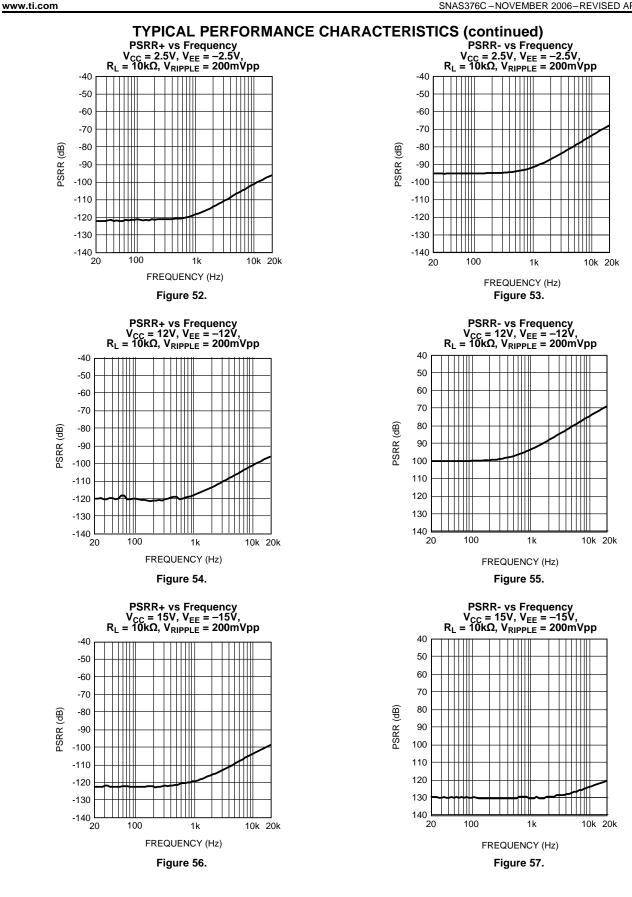




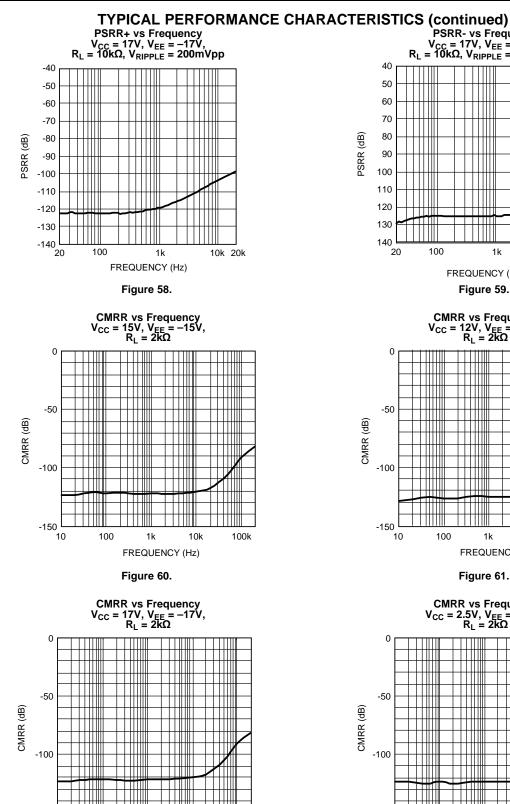


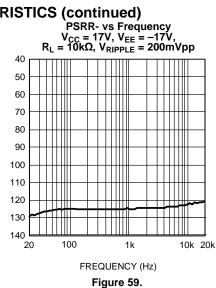






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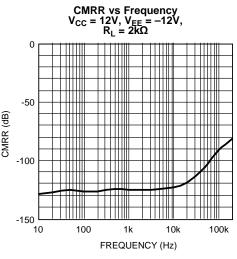
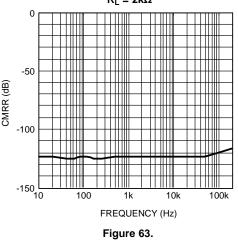


Figure 61.

CMRR vs Frequency V_{CC} = 2.5V, V_{EE} = -2.5V, R_L = 2k Ω



100

1k

Figure 62.

FREQUENCY (Hz)

10k

100k

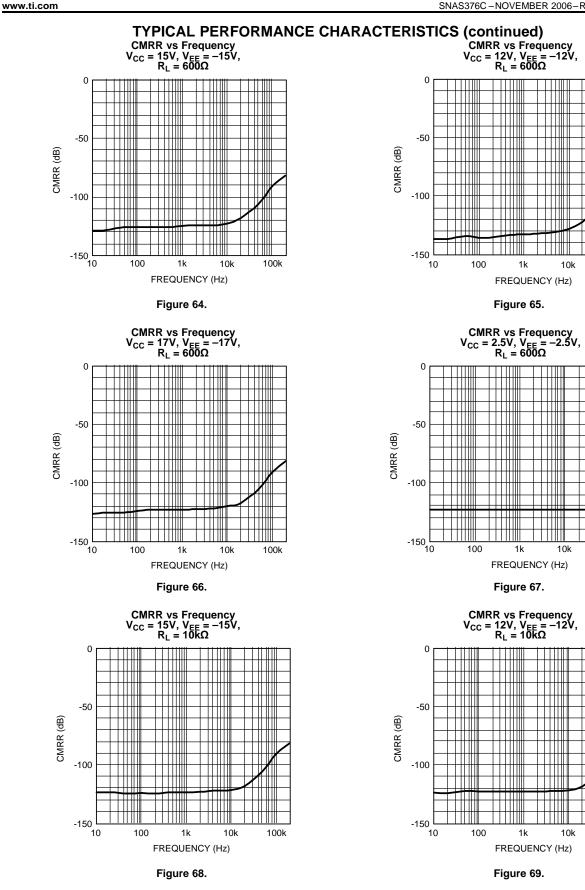
-150 , 10



100k

100k

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100k

CMRR (dB)

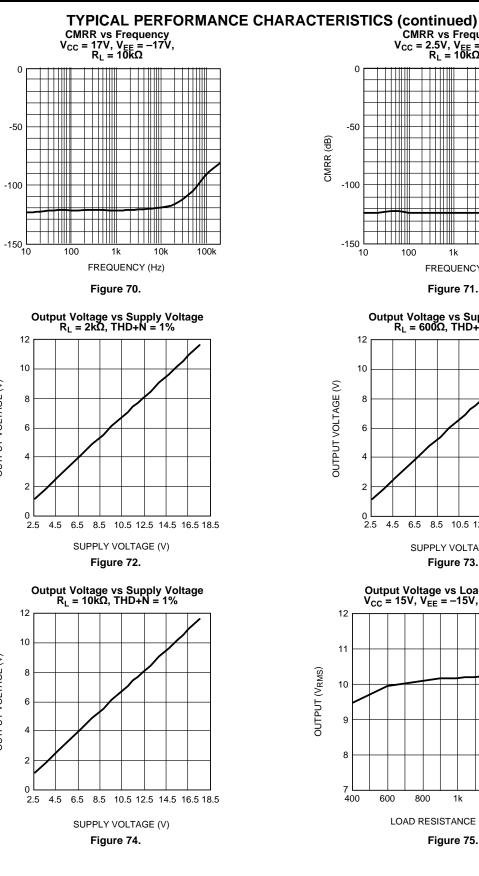
OUTPUT VOLTAGE (V)

OUTPUT VOLTAGE (V)

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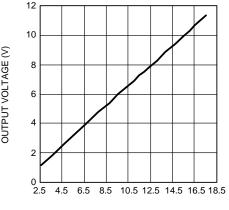
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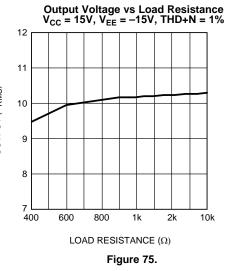
 $\label{eq:cmr} \begin{array}{l} \text{CMRR vs Frequency} \\ \text{V}_{\text{CC}} = 2.5\text{V}, \ \text{V}_{\text{EE}} = -2.5\text{V}, \\ \text{R}_{\text{L}} = 10\text{k}\Omega \end{array}$ 1k 10k 100k FREQUENCY (Hz)

Figure 71.

Output Voltage vs Supply Voltage $R_L = 600\Omega$, THD+N = 1%



SUPPLY VOLTAGE (V) Figure 73.





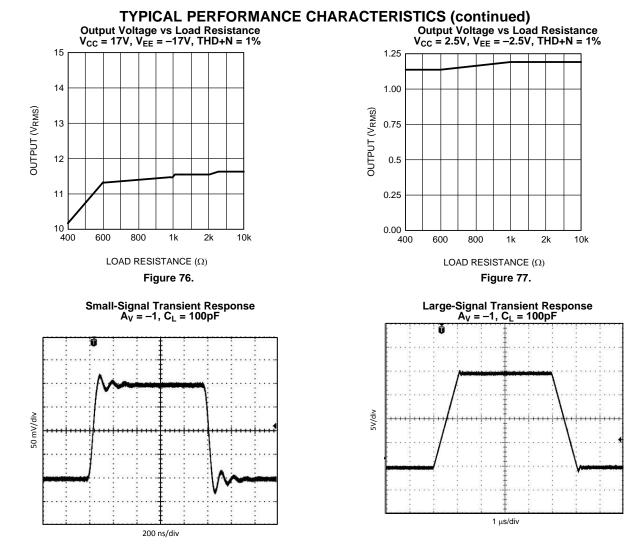
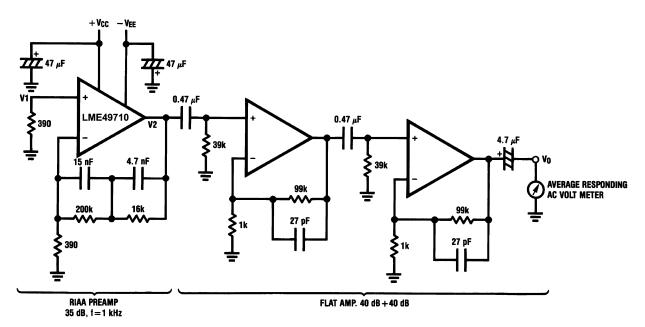


Figure 78.

Figure 79.

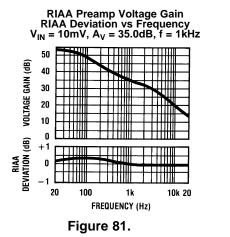
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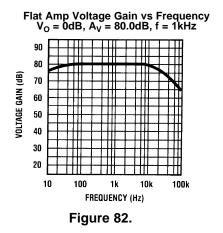




A. Complete shielding is required to prevent induced pick up from external sources. Always check with oscilloscope for power line noise.

Figure 80. Total Gain: 115 dB at f = 1 kHz Input Referred Noise Voltage: $e_n = V_0/560,000$ (V)





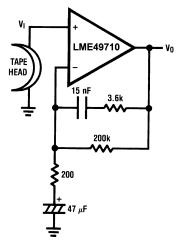


APPLICATION HINTS

The LME49710 is a high-speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 100pF must be isolated from the output. The most straight forward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

TYPICAL APPLICATIONS



 $\begin{array}{l} A_V = 34.5 \\ F = 1 \ kHz \\ E_n = 0.38 \ \mu V \\ A \ Weighted \end{array}$



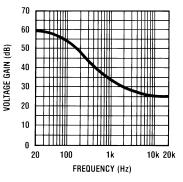
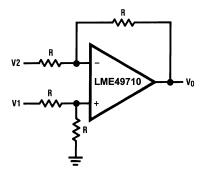


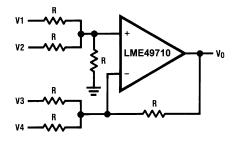
Figure 84. NAB Preamp Voltage Gain vs Frequency $V_{IN} = 10mV$, 34.5dB, f = 1kHz





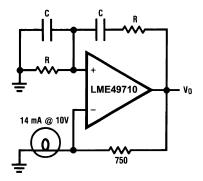
 $V_0 = V1 - V2$





 $V_0 = V1 + V2 - V3 - V4$

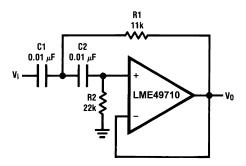
Figure 86. Adder/Subtracter



 $f_0 = \frac{1}{2\pi RC}$

Figure 87. Sine Wave Oscillator

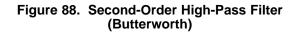


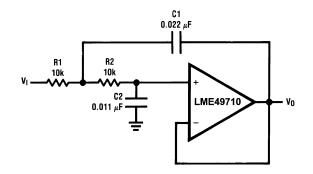


$$\text{if } C1\ =\ C2\ =\ C$$

$$R1 = \frac{\sqrt{2}}{2\omega_0 C}$$

 $R_2 = 2 \cdot R_1$ Illustration is $f_0 = 1 \text{ kHz}$



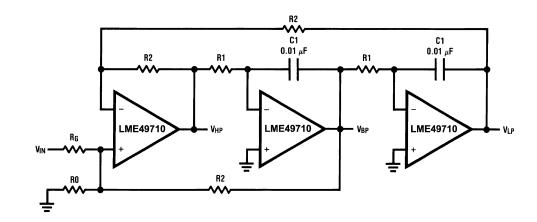


if R1 = R2 = R C1 = $\frac{\sqrt{2}}{\omega_0 R}$ C2 = $\frac{C1}{2}$

Illustration is $f_0 = 1 \text{ kHz}$

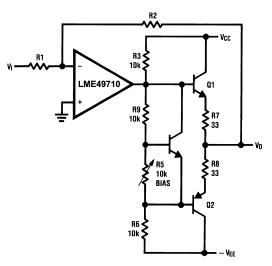
Figure 89. Second-Order Low-Pass Filter (Butterworth)

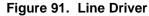


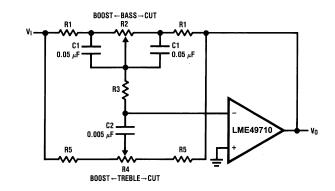


$$f_0 = \frac{1}{2\pi C1R1}, Q = \frac{1}{2} \left(1 + \frac{R2}{R0} + \frac{R2}{RG} \right), A_{BP} = QA_{LP} = QA_{LH} = \frac{R2}{RG}$$



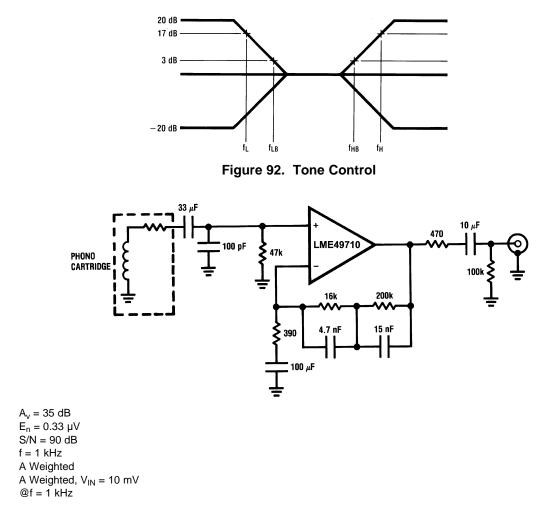






$$\begin{split} f_L &= \frac{1}{2\pi R2C1}, f_{LB} = \frac{1}{2\pi R1C1} \\ f_H &= \frac{1}{2\pi R5C2}, f_{HB} = \frac{1}{2\pi (R1 + R5 + 2R3)C2} \end{split}$$









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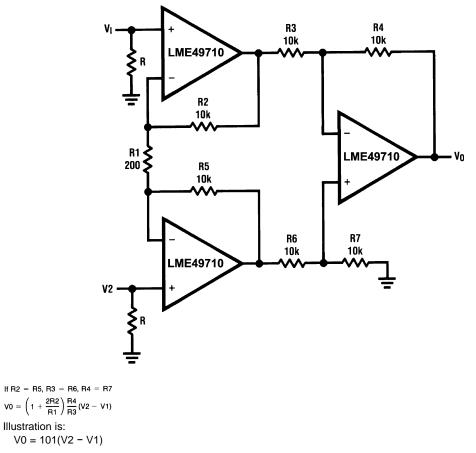


Figure 94. Balanced Input Mic Amp



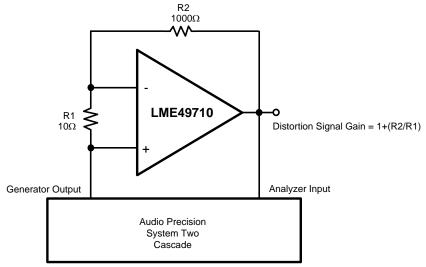
APPLICATION INFORMATION

DISTORTION MEASUREMENTS

The vanishingly low-residual distortion produced by LME49710 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49710's low-residual distortion is an input referred internal error. As shown in Figure 95, adding the 10Ω resistor connected between the amplifier's inverting and non-inverting inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 95.

This technique is verified by duplicating the measurements with high closed-loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.



Actual Distortion = AP Value/100

Figure 95. THD+N and IMD Distortion Test Circuit



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REVISION HISTORY

Rev	Date	Description
1.0	11/16/07	Initial release.
1.1	12/12/06	Added the Typical Performance curves.
1.2	01/15/07	Added more curves and input some text edits.
1.3	03/09/07	Fixed graphics 20210489 and 90.
С	04/04/13	Changed layout of National Data Sheet to TI format.



11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
LME49710HA/NOPB	ACTIVE	TO-99	LMC	8	20	Green (RoHS & no Sb/Br)	POST-PLATE	Level-1-NA-UNLIM	-40 to 85		Samples
LME49710MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	L49710 MA	Samples
LME49710MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	L49710 MA	Samples
LME49710NA/NOPB	ACTIVE	PDIP	Р	8	40	Green (RoHS & no Sb/Br)	SN	Level-1-NA-UNLIM	-40 to 85	LME 49710NA	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE OPTION ADDENDUM

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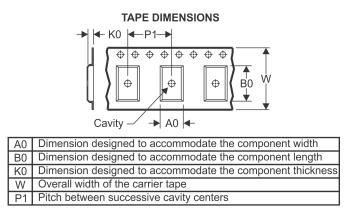
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal	
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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LME49710MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

8-Apr-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LME49710MAX/NOPB	SOIC	D	8	2500	349.0	337.0	45.0

LMC (O-MBCY-W8)

METAL CYLINDRICAL PACKAGE



- B. This drawing is subject to change without notice.
 - C. Leads in true position within 0.010 (0,25) R @ MMC at seating plane.
 - D. Pin numbers shown for reference only. Numbers may not be marked on package.
 - E. Falls within JEDEC MO-002/TO-99.



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



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